

Data Sheet

2.5V Drive Nch MOSFET

RSU002N06

Structure

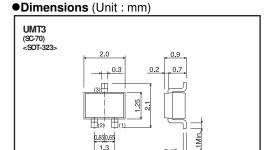
Silicon N-channel MOSFET

●Features

- 1) High speed switing.
- 2) Small package(UMT3).
- 3) Low voltage drive(2.5V drive).

Application

Switching

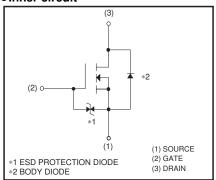


Abbreviated symbol: RK

Packaging specifications

	9 -1		
Туре	Package	Taping	
	Code	T106	
	Basic ordering unit (pieces)	3000	
RSU002N06		0	

●Inner circuit



● Absolute maximum ratings (Ta = 25°C)

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Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DSS}	60	V
Gate-source voltage		V_{GSS}	<u>+2</u> 0	V
Drain current	Continuous	I_D	±250	mA
	Pulsed	I _{DP} *1	±1	Α
Source current	Continuous	I _S	150	mA
(Body Diode)	Pulsed	I _{SP} *1	1	Α
Power dissipation		P_D *2	200	mW
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	-55 to +150	°C

^{*1} Pw≤10µs, Duty cycle≤1%

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth (ch-a)*	625	°C / W

^{*} Each terminal mounted on a recommended land.

^{*2} Each terminal mounted on a recommended land.

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	1	-	±10	μ A	$V_{GS} = \pm 20V, V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	60	1	-	V	I _D =1mA, V _{GS} =0V
Zero gate voltage drain current	I_{DSS}	1	-	1	μ A	V_{DS} =60V, V_{GS} =0V
Gate threshold voltage	V _{GS (th)}	1.0	-	2.3	V	$V_{DS}=10V$, $I_{D}=1mA$
		1	1.7	2.4	Ω	$I_D = 250 \text{mA}, V_{GS} = 10 \text{V}$
Static drain-source on-state	ь *	1	2.1	3.0		$I_D = 250 \text{mA}, V_{GS} = 4.5 \text{V}$
resistance	R _{DS (on)}	1	2.3	3.2		I _D =250mA, V _{GS} =4.0V
		1	3.0	12.0		$I_D=10$ mA, $V_{GS}=2.5$ V
Forward transfer admittance	I Y _{fs} I*	0.25	-	-	S	$I_D = 250 \text{mA}, V_{DS} = 10 \text{V}$
Input capacitance	C _{iss}	1	15	-	pF	V _{DS} =25V
Output capacitance	C _{oss}	1	4.5	-	pF	V _{GS} =0V
Reverse transfer capacitance	C_{rss}	1	2.0	-	pF	f=1MHz
Turn-on delay time	t _{d(on)} *	1	3.5	-	ns	$I_D=100$ mA, $V_{DD}=30$ V
Rise time	t _r *	-	5	-	ns	V _{GS} =10V
Turn-off delay time	t _{d(off)} *	-	18	-	ns	R _L ≒300Ω
Fall time	t _f *	-	28	-	ns	$R_G=10\Omega$

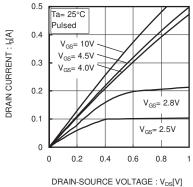
^{*}Pulsed

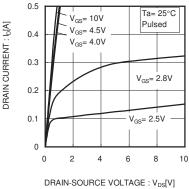
●Body diode characteristics (Source-Drain) (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	V _{SD} *	-	-	1.2	V	I _s =250mA, V _{GS} =0V

^{*}Pulsed

Electrical characteristic curves





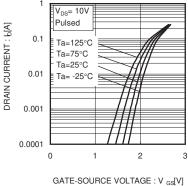
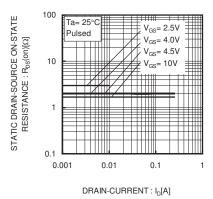


Fig.1 Typical Output Characteristics(I)

Fig.2 Typical Output Characteristics(II)

Fig.3 Typical Transfer Characteristics



DRAIN-CURRENT: I₀[A]

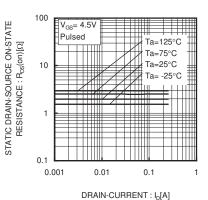
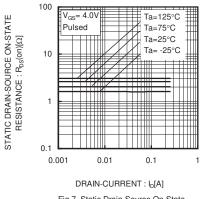
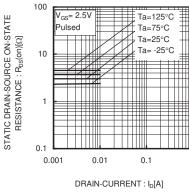


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current([)

Fig.5 Static Drain-Source On-State Resistance vs. Drain Current([[])

Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(Ⅲ)





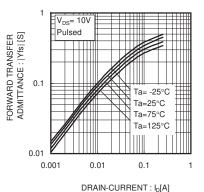
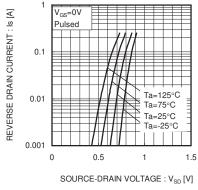
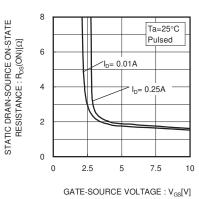


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

Fig.8 Static Drain-Source On-State
Resistance vs. Drain Current(IV)

Fig.9 Forward Transfer Admittance vs. Drain Current





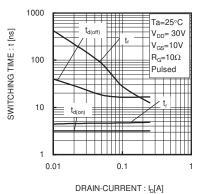


Fig.10 Reverse Drain Current vs. Sourse-Drain Voltage

Fig.11 Static Drain-Source On-State
Resistance vs. Gate Source Voltage

Fig.12 Switching Characteristics

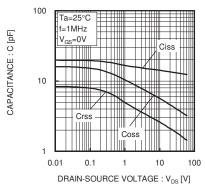


Fig.13 Typical Capacitance vs. Drain-Source Voltage

●Measurement circuits

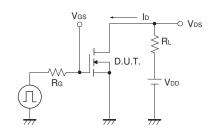


Fig.1-1 Switching time measurement circuit

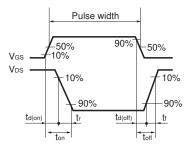


Fig.1-2 Switching waveforms

●Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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